Atomistic Simulation of Undissociated 60° Basal Dislocation in Wurtzite GaN.

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ABSTRACT
We have carried out computer atomistic simulations, based on an efficient density functional based tight binding method, to investigate the core configurations of the 60° basal dislocation in GaN wurtzite. Our energetic calculations, on the undissociated dislocation, demonstrate that the glide configuration with N polarity is the most energetically favorable over both the glide and the shuffle sets.

Keywords: Gallium Nitride; 60° Basal Dislocation; Core Structure; Energy; Tight-binding; SCC-DFTB

1. Introduction
Wurtzite GaN layers were initially grown along the [0001] direction, also called polar direction [1]. This led to the fabrication of optoelectronic devices, based on heterostructures, which are strongly affected by spontaneous and piezoelectric polarization effects [2]. These effects are at the origin of the occurrence of a high internal electrostatic field which increases the separation between electrons and holes and thus reducing the overlap of their wavefunctions [2]. The latter causes a strong current dependence of the emission energy and a red shift of optical transitions as well as reduces the emission efficiency of optoelectronic devices [2]. The polarization-related effects in wurtzite GaN heterostructures can be completely avoided by adopting growth on alternative orientations. Hence, various growth directions were explored. These were the non-polar directions: [11̅2̅0], [0001]) and the semi-polar directions: [10̅1̅0], [10̅1̅1] and [11̅2̅2] [3]. Then, GaN/AlGaN heterostructures grown along non-polar or semi-polar directions were proven to be free from polarization effects and thus demonstrate a clear improvement of their optical properties with respect to those elaborated along the polar direction.

The nature of threading dislocations contained in a wurtzite GaN layer is directly related to the direction of its growth. If the growth direction is [0001], i.e. the polar direction, the threading dislocations are perfect prismatic dislocations, which can be edge, screw or mixed [4]. However, if the growth direction is [11̅2̅0], i.e. the non-polar direction, the threading dislocations can be perfect or partial basal dislocations [4]. Perfect basal dislocations are screw and 60° -mixed, while partial basal dislocations are Shockley (edge, 30°-mixed), Frank and Frank-Shockley partials [5].

During the last decade, threading prismatic dislocations were extensively investigated in gallium nitride, at both experimental and theoretical levels [4]. For these dislocations, models for their core structures were proposed and their impact on the electronic properties of GaN was nearly elucidated [6-8]. The body of work dedicated to basal dislocations in GaN still insufficient compared to that to prismatic dislocations [4], while among basal dislocations, partials [9] were more investigated regarding the perfect ones [10,11]. The perfect screw dislocation was investigated atomistically and the energetic hierarchy of its core configurations was established by Belabbas et al. [12]. The perfect 60° dislocation was studied in cubic GaN by Blumenau et al. [13] but unfortunately no theoretical report exists for the wurtzite phase. At the experimental level, the perfect 60° dislocation was observed by using electron microscopy. By combining conventional transmission electron microscopy and cathodoluminescence measurements, Albrecht et al. [14] investigated the 60° dislocation in wurtzite GaN and analyzed its electronic and optical ac-
tivities. They found it to be likely responsible for a parasitic luminescence around 2.9 eV. However, due to the limited resolution of their used microscope, the previous authors were not able to establish if this observed behavior is that of a full or a dissociated dislocation. In a subsequent study, Niermann et al. [15] have observed a dissociated 60° dislocation by using high resolution transmission electron microscopy. The separation between the two resulting Shockley partials was found to be smaller than 2 nm.

In the present contribution, we have carried out computer atomistic simulations to investigate the core configurations of the 60° basal dislocation in GaN wurtzite.

2. Models and Simulation Details

The 60° basal dislocation has a mixed character (edge and screw). In the wurtzite crystal structure, this dislocation is perfect and has its line along the [11̅0] direction and its Burgers vector is a/3[11̅2] which has a magnitude equal to a (a = 3.18 Å stands for the basal lattice vector of GaN). The 60° basal dislocation may have several core configurations, which depends on the position of its centre. If the latter is located between two narrowly spaced {0001} planes, called the glide set, the dislocation will have a glide configuration. However, if the centre of the dislocation is situated between two widely spaced {0001} planes, called the shuffle set, the dislocation will have a shuffle configuration. As gallium nitride is a compound semiconductor, a glide (or a shuffle) core configuration may exist in two different polarities: gallium or nitrogen. This depends on the nature of the ending atom at the additional half plane, which is at the origin of the edge component of the dislocation.

The 60° basal dislocation was modeled atomistically by using the so-called supercell-cluster hybrid model [6-8]. The atoms at the model’s lateral surface (Ga/N) have to be saturated by fractionally charged (1.25e/0.75e) pseudo-hydrogen atoms which allow getting rid of dangling bonds and their associated unwanted gap states [6-8]. The supercell-cluster hybrids were at least doubled along [11̅0] direction in order to take into account any possible reconstruction along the dislocation line. The size of the models considered here is ranging from 750 to 1000 atoms and their lateral extension is typically about 26 Å. Although the lateral extension of the model is finite, periodic boundary conditions were applied laterally to the dislocation line while including a 50 Å of vacuum. The equilibrium atomic positions were obtained through a minimization procedure based on the conjugate gradient algorithm where energies and forces are evaluated by using the SCC-DFTB method [16]. During this step all the atoms, including those at the model’s lateral surfaces, were allowed to relax freely. The equilibrium is reached when the maximum force acting on each atom of the system is well below 0.0001 a.u.

3. Results and Discussion

For the 60° basal dislocation, we have considered four core configurations: a shuffle configuration with nitrogen polarity (60° -SN), a shuffle configuration with gallium polarity (60° -SGa), a glide configuration with a gallium polarity (60° -GGa) and a glide configuration with nitrogen polarity (60° -GN). These core configurations are represented respectively in figures (1.a, 1.b, 1.c, 1.d). In the following we will present and discuss our results concerning the atomic description of the previous core configurations and their energetics.

3.1. Atomic Core Structure

The 60° -SN core configuration (Figure 1(a)) presents a structure with an asymmetric 8-atoms ring. This is different from the 8-atoms ring structure exhibited by the prismatic edge dislocation which processes mirror plane symmetry [17]. All the atoms forming the core are fully coordinated except those of the column (1) which involves dangling bonds (Figure 1(a)). The most compressed bonds (-8.21%) are established between the atoms of columns (1) and (8), while the most stretched bonds (+13.33%) are established between the atoms of columns (5) and (6). The chemical bonds involved in the core present an angular dispersion ranging from 93° to 128°.

The 60° -SGa core configuration (Figure 1(b)) has, as in the previous one, a structure with an asymmetric 8-atoms ring. However, while the 60° -SN configuration exhibits a single period structure, a complex reconstruction takes place in the 60° -SGa configuration, leading to doubling its period along the dislocation line. This reconstruction consists in establishing alternated Ga-Ga bonds (2.81 Å) between the atoms of columns (1) and (5), while occurring in column (6) dangling bonds within a 2a period. In this core configuration, the most compressed Ga-N bonds (-7.18%) are involved by the low coordinated atoms of column (1) and those of column (8). The most stretched Ga-N bonds (+17.44%) are established between the atoms of columns (5) and (6). The most extreme bond angles (79° and 154°) are recorded for the atoms of column (5).

The 60° -GGa core configuration (Figure 1(c)) exhibits a structure with an asymmetric 5/7-atoms ring. This core configuration includes only Ga-Ga bonds separating the 5-atoms and 7-atoms rings, which make it different from the symmetric core configuration of a prismatic edge dislocation where both Ga-Ga and N-N are separating the two atomic rings [17]. In the configuration 60° -GGa, the Ga-Ga bonds (2.32 Å) are established between the atoms of columns (3) and (9). The
latter contains under-coordinated Ga atoms. The most compressed Ga-N bonds (-5.64%) are involved between the (3) and (9) atomic columns, while the most stretched bonds (+10.77%) are established between the atoms of columns (5) and (6) and those of columns (6) and (7). The most extreme bond angles (90° and 138°) are recorded for the atoms of column (3).

The 60°-GaN core configuration (Figure 1(d)) has a structure with an asymmetric 5/7-atoms ring, which contains some N-N bonds. The considerable difference in bond lengths between the N-N bonds (1.58 Å), involved in this configuration, and the Ga-Ga bonds, involved in the previous configuration, makes the 60°-GaN core configuration less spatially extended than the 60°-Ga core configuration. In the configuration 60°-GaN, the column (9) does contain under-coordinated N atoms. The most compressed Ga-N bonds (-6.67%) are established between the atoms of columns (8) and (9). The most stretched bonds (+7.18%) are involved by, in one hand, the atoms of columns (2) and (3) and, in the other hand, by the atoms of columns (5) and (6). The bond angles present a dispersion ranging from 92° to 134°.

### 3.2. Energetics

The energetic hierarchy of the four core configurations of the 60° basal dislocation was accessed through a combination of continuum elasticity theory and atomistic calculations based on the SCC-DFTB method. The total strain energy ($E_{\text{total}}$) associated with a dislocation can be represented as a sum of elastic ($E_{\text{elastic}}$) and core ($E_{\text{core}}$) contributions:

$$E_{\text{total}} = E_{\text{elastic}} + E_{\text{core}}$$  

within linear elasticity, the elastic strain energy per unit length stored in a cylinder of radius $R$ around the dislocation is given by the relation [18]:

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**Figure 1.** Ball and stick models for relaxed core configurations of the mixed 60° basal dislocation, projected along the [1120] direction. Black balls represent gallium atoms and the white ones nitrogen atoms. (a): View of the 60°-SN core configuration. (b): View of the 60°-SGa core configuration. (c): View of the 60°-G Ga core configuration. (d): View of the 60°-G N core configuration.
\[ E_{\text{elastic}} = A \ln \left( R / R_c \right) \quad \text{for} \quad R > R_c \]  \hspace{1cm} (2)

where \( R_c \) is the dislocation core radius. For a mixed type dislocation, the pre-logarithmic factor is related to both the edge and screw components of the Burgers vector of the dislocation (\( b_e \) and \( b_s \) respectively) and it is given, within anisotropic elasticity, by the relation [18]:

\[ A = (1 / 4\pi) (K_e b_e^2 + K_s b_s^2) \]  \hspace{1cm} (3)

In the case of a mixed basal dislocation, the energy factors \( K_e \) and \( K_s \), associated respectively with the edge and the screw components, are given by the relations [18]:

\[ K_e = (\sqrt{C_{11}C_{33} + C_{13}}) \left( \frac{C_{44} \left( \sqrt{C_{11}C_{33} - C_{13}} \right) - C_{13}}{C_{33} \left( \sqrt{C_{11}C_{33} + C_{13}} + 2C_{44} \right)} \right)^{1/2} \]  \hspace{1cm} (4a)

and

\[ K_s = \sqrt{C_{44} C_{66}} \]  \hspace{1cm} (4b)

where \( C_{ij} \) are the elastic constants of the material.

Within the SCC-DFTB method, one can define the excess energy of a single atom as its difference in energy in the system with presence of the defect and that in bulk material. Hence, the total strain energy \( E_{\text{total}} \) contained in a cylinder of radius \( R \) around the dislocation is evaluated by summing the excess of energy related to individual atoms belonging to this area. In order to determine the core parameters of the dislocation, i.e. core energy and core radius, we plotted the total strain energy \( E_{\text{total}} \) versus \( \ln(R) \), for the four considered core configurations (Figure 2). These curves exhibit three distinct domains: a central linear region bordered by two non-linear ones.

The linear region represents the so-called elastic region while the non-linear region close to the centre of the dislocation represents the so-called core region. The appearance of a quick enhancement of the strain energy, in the second non-linear region, is attributed to surface effects.

Fitting the linear parts of the strain energy curves with equation (2) allowed us to determine the values of the pre-logarithmic factor \( (A_{fit}) \) which represents the slope of these curves. The obtained values are ranging from -1.3% to -10.4% (Table 1) with respect to theoretical value of \( A = 0.77 \text{eV/Å} \), evaluated by using equation (3) and the experimental values of the elastic constants.

The core radius of a particular core configuration is defined as the value of the radius from which the strain energy curve cesses of being linear, when going to the centre of the dislocation. The core energy is defined as the value of the energy corresponding to the core radius [7]. The obtained core energies and radii of the four core configurations of the 60° basal dislocation are summarized in Table 1. Then, the comparison of the core energies, evaluated at a common radius of 6Å, shows that within the glide set, the configuration with a nitrogen core (60°-G_N) is energetically favorable over the configuration with a gallium core (60°-G_Ga). However, the opposite is observed in the shuffle set, where the configuration with a gallium core (60°-S_Ga) has lower core energy than the configuration with a nitrogen core (60°-S_N). The core configuration 60°-G_N was found to be the most energetically favorable over both the glide and the shuffle sets. Otherwise, our calculations show that the core energy difference of the glide configurations (0.53 eV/Å) is higher than that of the shuffle ones (0.11 eV/Å).

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**Figure 2.** The total strain energy per unit length stored in a cylinder of radius \( R \) as a function of \( \ln(R) \) for different core configurations of the 60° basal dislocation: 60°-S_N, 60°-S_Ga, 60°-G_N and 60°-G_Ga.
Table 1. The calculated core radii ($R_c$) core energies ($E_c$) of the different configurations of the $60^\circ$ dislocation. To facilitate comparison between dislocations with different core radii, the core energy ($E'_c$) corresponding to a radius of 6Å is introduced. Also indicated, the calculated pre-logarithmic factors: ($A_{\text{fit}}$) (SCC-DFTB), ($A$) (anisotropic elasticity theory) of the different core configurations of the $60^\circ$ dislocation.

<table>
<thead>
<tr>
<th></th>
<th>$60^\circ$-$SN$</th>
<th>$60^\circ$-$SN_G$</th>
<th>$60^\circ$-$GGa$</th>
<th>$60^\circ$-$GGa_N$</th>
</tr>
</thead>
<tbody>
<tr>
<td>$A_{\text{fit}}$ (eV/Å)</td>
<td>0.720</td>
<td>0.690</td>
<td>0.760</td>
<td>0.740</td>
</tr>
<tr>
<td>$A$ (eV/Å)</td>
<td>0.770</td>
<td>0.770</td>
<td>0.770</td>
<td>0.770</td>
</tr>
<tr>
<td>$R_c$ (Å)</td>
<td>3.720</td>
<td>3.760</td>
<td>4.260</td>
<td>3.820</td>
</tr>
<tr>
<td>$E_c$ (eV/Å)</td>
<td>1.530</td>
<td>1.440</td>
<td>1.200</td>
<td>1.660</td>
</tr>
<tr>
<td>$E'_c$ (@ R=6Å) (eV/Å)</td>
<td>1.874</td>
<td>1.762</td>
<td>1.460</td>
<td>1.994</td>
</tr>
</tbody>
</table>

One can consider that the core energy of a given dislocation has two contributions: $i$- a contribution due to heavily strained bonds (non-linear strain) and $ii$- a second contribution which is due to dangling bonds. Based on the latter consideration, one can attempt to understand the obtained energetic hierarchy of the core configurations of the $60^\circ$ dislocation.

As the two glide core configurations ($60^\circ$-$SN$, $60^\circ$-$GGa$) exhibit comparable bond distortions, one may argue that the contribution which makes the difference in the establishment of their energetic hierarchy is that of dangling bonds. This implies that N-dangling bonds are less energetic than the Ga-dangling bonds. As this has to be also valid for the shuffle configurations, one may expect that the $60^\circ$-$SN$ configuration is more energetically favorable than the $60^\circ$-$SGa$ configuration. However, the inversion of the energetic hierarchy revealed by our present calculations is directly related to the reconstruction that occurs at the $60^\circ$-$SN_G$ core. Indeed, by a rearrangement of core atoms, the reconstruction allows getting rid of Ga-dangling bonds and then leads to a particular bonding state which is less energetic than N-dangling bonds.

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